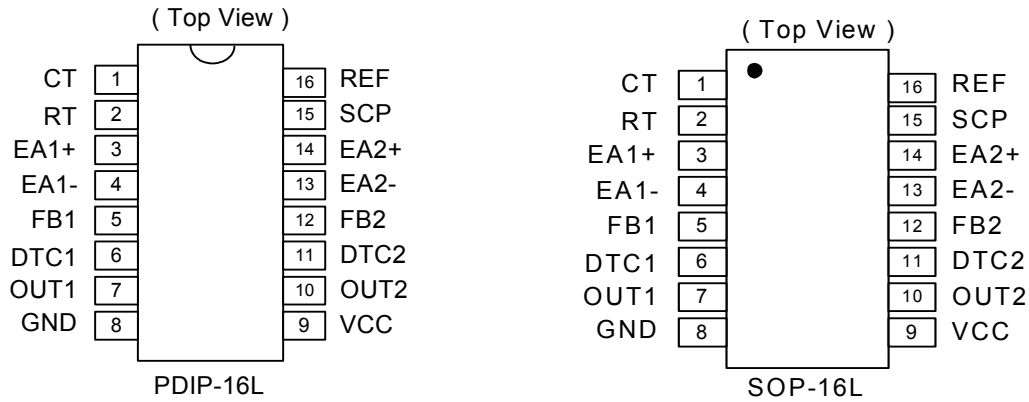


Pin Assignments



Pin Descriptions

Name	Description
CT	Timing Capacitor
RT	Timing Resistor
EA+	Error Amplifier Input(+)
EA -	Error Amplifier Input(-)
FB	Feedback Loop Compensation
DTC	Dead Time Control
OUT	Pre-driver Output
GND	Ground
VCC	Supply Voltage
SCP	Short Circuit Protection
REF	Voltage Reference

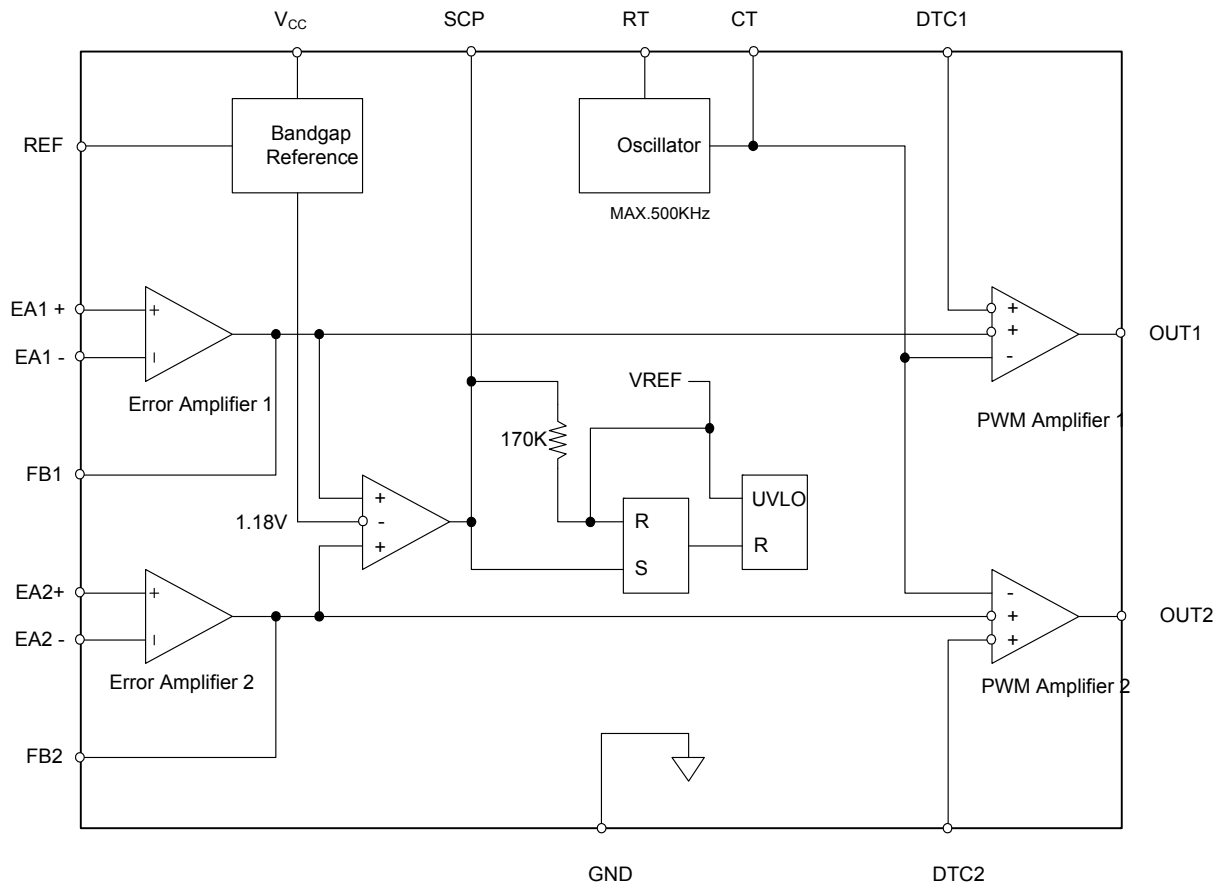
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MONOLITHIC DUAL CHANNEL PWM CONTROLLER

Block Diagram



Absolute Maximum Ratings

Symbol	Parameter	Rating	Unit
V_{CC}	Supply Voltage	40	V
V_I	Amplifier Input Voltage	20	V
V_O	Collector Output Voltage	40	V
I_O	Collector Output Current	21	mA
T_{OP}	Operating Temperature Range	-20 to +85	°C
T_{ST}	Storage Temperature Range	-65 to +150	°C
T_{LEAD}	Lead Temperature 1.6 mm (1/16 inch) from Case for 5 Seconds	245	°C

Recommended Operating Conditions

Symbol	Parameter	Min.	Max.	Unit
V_{CC}	Supply Voltage	3.6	40	V
V_I	Amplifier Input Voltage	1.05	1.45	V
V_O	Collector Output Voltage		40	V
I_O	Collector Output Current		20	mA
I_{FB}	Current into Feedback Terminal		45	μ A
R_F	Feedback Resistor	100		k Ω
C_T	Timing Capacitor	150	15000	pF
R_T	Timing Resistor	5.1	100	k Ω
F_{OSC}	Oscillator Frequency	1	500	KHz
T_{OP}	Operating Free-air Temperature	-20	85	$^{\circ}$ C

Electrical Characteristics ($T_A = 25^{\circ}$ C, $V_{CC} = 6$ V, $f = 200$ KHz)

Reference (REF)

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
V_O	Output Voltage (pin 16)	$I_O = 1$ mA	2.4	2.5	2.6	V
	Output Voltage Change with Temperature	$T_A = -20^{\circ}$ C ~ 25° C $T_A = 25^{\circ}$ C ~ 85° C		-0.1 -0.2	± 1 ± 1	%
V_{DLI}	Input Stability	$V_{CC} = 3.6$ V ~ 40 V		2	12.5	mV
V_{DLO}	Output Stability	$I_O = 0.1$ mA ~ 1 mA		1	7.5	mV
I_O	Short-circuit Output Current	$V_O = 0$	3	10	30	mA

Under voltage lockout (UVLO)

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
V_{UT}	Upper Threshold Voltage (V_{CC})	$I_{O(REF)} = 0.1$ mA $T_A = 25^{\circ}$ C		2.65		V
V_{LWT}	Lower Threshold Voltage (V_{CC})			2.45		V
V_{HT}	Hysteresis (V_{CC})		80	200		mV

Electrical Characteristics (Continued)
Short-circuit protection (SCP) control

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
V_{IT}	Input Threshold Voltage	$T_A = 25^\circ\text{C}$	0.65	0.7	0.75	V
V_{STB}	Standby Voltage	No pull up	140	185	230	mV
V_{LT}	Latched Input Voltage	No pull up		60	120	mV
I_{SCP}	Input (Source) Current	$V_I = 0.7\text{V}$, $T_A = 25^\circ\text{C}$	-10	-15	-20	μA
V_{CT}	Comparator Threshold Voltage (FB)			1.18		V

Oscillator (OSC)

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
F_{OSC}	Frequency	$C_T = 330\text{ pF}$, $R_T = 10\text{ K}\Omega$		200		KHz
ΔF_{OSC}	Standard Deviation of Frequency	$C_T = 330\text{ pF}$, $R_T = 10\text{ K}\Omega$		10		%
	Frequency Change with Voltage	$V_{CC} = 3.6\text{V} \sim 40\text{V}$		1		
	Frequency Change with Temperature	$T_A = -20^\circ\text{C} \sim 25^\circ\text{C}$		-0.4	± 2	
		$T_A = 25^\circ\text{C} \sim 85^\circ\text{C}$		-0.2	± 2	

Dead-time control (DTC)

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
I_{BDT}	Input Bias Current				1	μA
I_{DT}	Latch Mode (Source) Current	$T_A = 25^\circ\text{C}$	-80	-145		
V_{DT}	Latched Input Voltage	$I_O = 40\mu\text{A}$	2.3			V
V_{T0}	Input Threshold Voltage at $f = 10\text{ KHz}$	Zero duty cycle		2.05	2.25	
V_{T100}		Maximum duty cycle	1.2	1.45		

Error-amplifier

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
V_{IO}	Input Offset Voltage	$V_O (\text{FB}) = 1.25\text{V}$			± 6	mV
I_{IO}	Input Offset Current	$V_O (\text{FB}) = 1.25\text{V}$			± 100	nA
I_{IB}	Input Bias Current	$V_O (\text{FB}) = 1.25\text{V}$		160	500	nA
V_{CM}	Common-mode Input Voltage Range	$V_{CC} = 3.6\text{V} \sim 40\text{V}$	1.05 to 1.45			V
AV	Open-loop Voltage Amplification	$R_F = 200\text{ K}\Omega$	70	80		dB
GBW	Unity-gain Bandwidth			1.5		MHz
CMRR	Common-mode Rejection Ratio		60	80		dB
V_{OH}	Max. Output Voltage		$V_{ref}-0.1$			V
V_{OL}	Min. Output Voltage				1	V
I_{OI}	Output (Sink) Current (FB)	$V_{ID} = -0.1\text{V}$, $V_O = 1.25\text{V}$	0.5	1.6		mA
I_{OO}	Output (Source) Current (FB)	$V_{ID} = 0.1\text{V}$, $V_O = 1.25\text{V}$	-45	-70		μA

Electrical Characteristics (Continued)
Output section

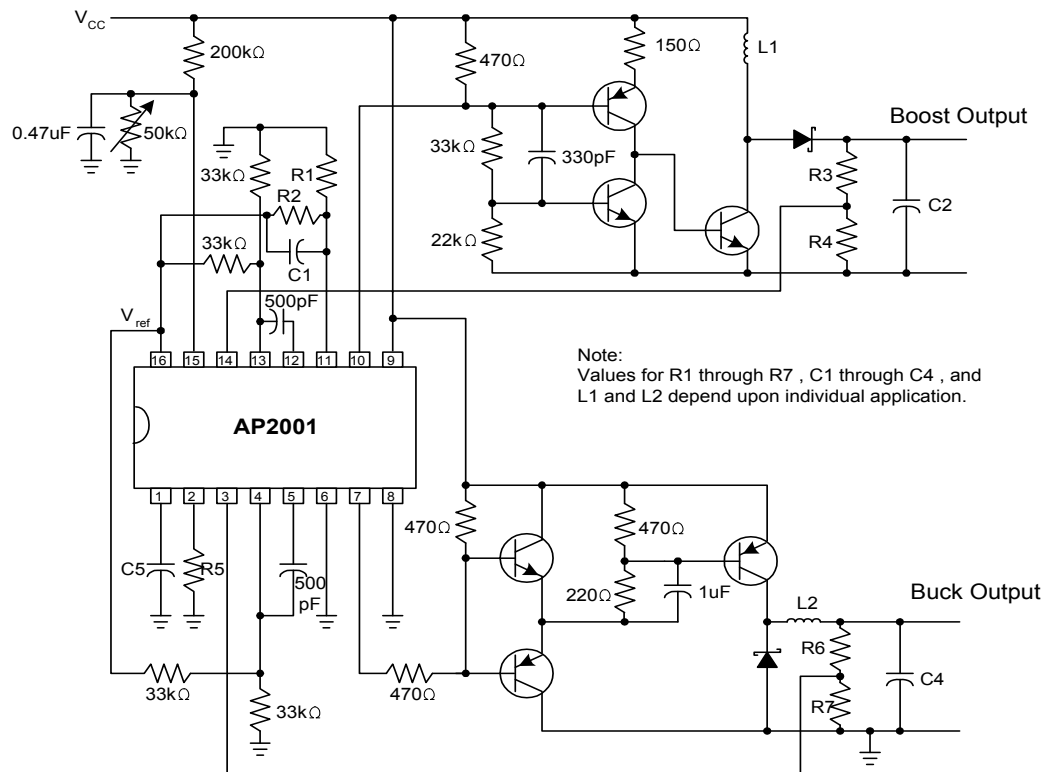
Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
I_{LEAK}	Leakage Current	$V_O = 40V$			10	μA
V_{SAT}	Output Saturation Voltage	$I_O = 10\text{ mA}$		1.2	2	V
I_{SC}	Short-circuit Output Current	$V_O = 6V$		90		mA

PWM comparator

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
V_{T0}	Input Threshold Voltage at $f = 10\text{ KHz}$ (FB)	Zero duty cycle		2.05	2.25	V
V_{T100}		Maximum duty cycle	1.2	1.45		V

Total device

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
I_{CCS}	Standby Supply Current	Off-state		2.5	3.0	mA
I_{CCA}	Average Supply Current	$R_T = 10\text{ K}\Omega$		2.8	3.5	mA

Typical Application Circuit

Dual output DC/DC converter

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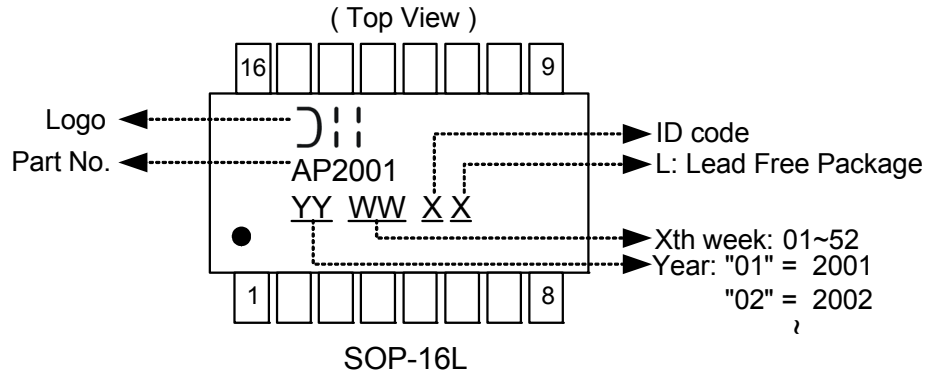


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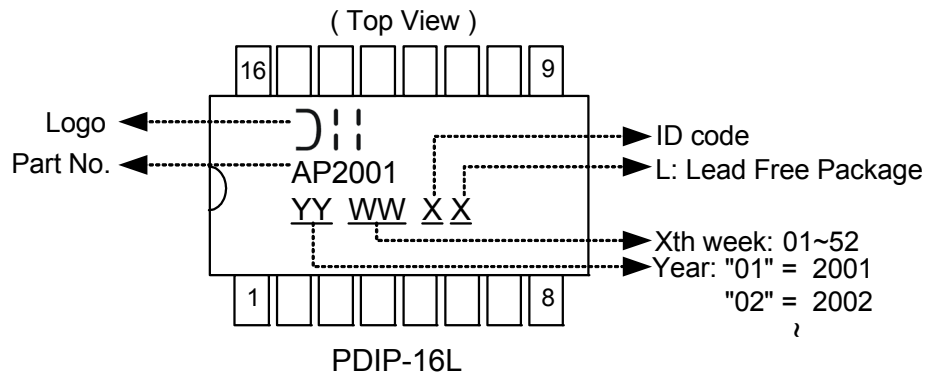
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Marking Information

(1) SOP-16L



(2) PDIP-16L



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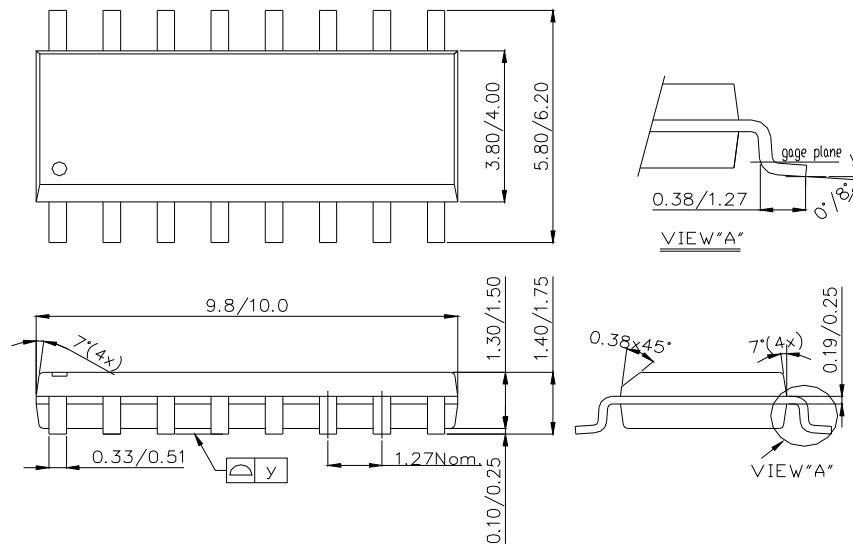


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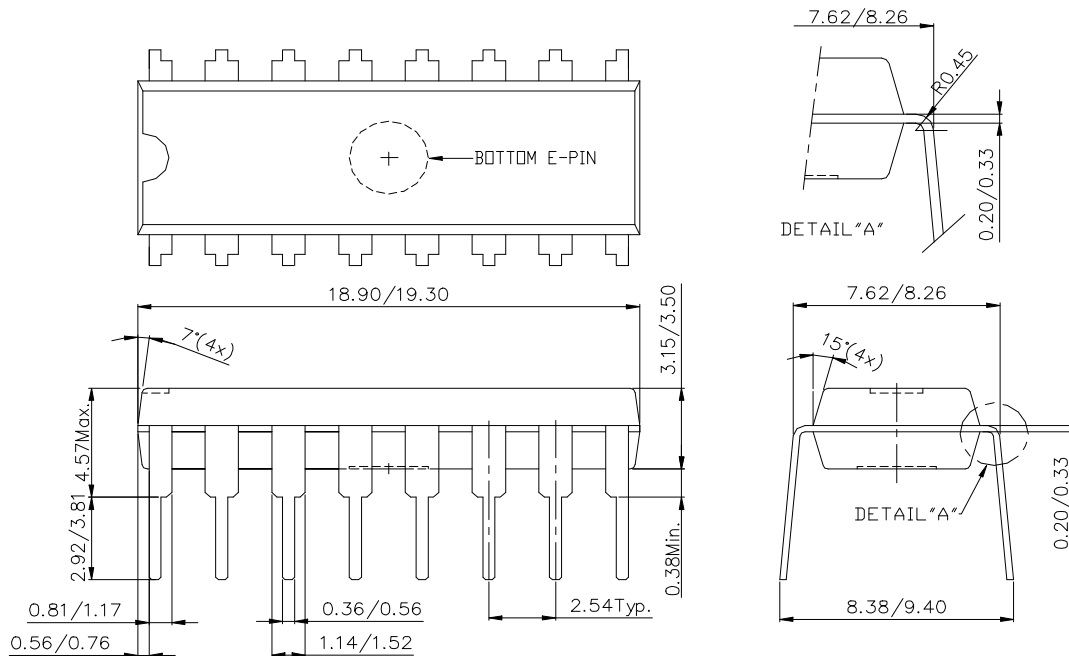
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Package Information

(1) Package Type: SOP-16L



(2) Package Type: PDIP-16L



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MONOLITHIC DUAL CHANNEL PWM CONTROLLER

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